Triacs Silicon Bidirectional Thyristors

Designed for high performance full-wave ac control applications where high noise immunity and high commutating di/dt are required.

Features

- Blocking Voltage to 800 Volts
- On-State Current Rating of 25 Amperes RMS at 95°C
- Uniform Gate Trigger Currents in Three Quadrants
- High Immunity to dV/dt 500 V/µs minimum at 150°C
- Minimizes Snubber Networks for Protection
- Industry Standard TO-220AB Package Internally Isolated
- High Commutating dI/dt 4.0 A/ms minimum at 150°C
- Internally Isolated (2500 V_{RMS})
- These are Pb–Free Devices

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Off–State Voltage (Note 1) ($T_J = -40$ to 150°C, Sine Wave, 50 to 60 Hz, Gate Open)	V _{DRM,} V _{RRM}		V
BTA25H-600CW3G BTA25H-800CW3G		600 800	
On-State RMS Current (Full Cycle Sine Wave, 60 Hz, T_{C} = 95°C)	I _{T(RMS)}	25	A
Peak Non-Repetitive Surge Current (One Full Cycle Sine Wave, 60 Hz, $T_{C} = 25^{\circ}C$)	I _{TSM}	250	A
Circuit Fusing Consideration (t = 8.3 ms)	l ² t	260	A ² sec
Non-Repetitive Surge Peak Off-State Voltage (T_J = 25°C, t = 8.3 ms)	V _{DSM/} V _{RSM}	V _{DRM} /V _{RRM} +100	V
Peak Gate Current (T_J = 150°C, t \leq 20 $\mu s)$	I _{GM}	4.0	А
Average Gate Power ($T_J = 150^{\circ}C$)	P _{G(AV)}	0.5	W
Operating Junction Temperature Range	ТJ	-40 to +150	°C
Storage Temperature Range	T _{stg}	-40 to +150	°C
RMS Isolation Voltage (t = 300 ms, R.H. \leq 30%, T _A = 25°C)	V _{iso}	2500	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

 V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

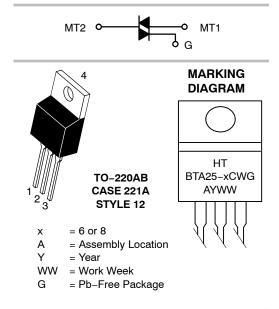
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TRIACS 25 AMPERES RMS 600 thru 800 VOLTS



PIN ASSIGNMENT				
Main Terminal 1				
Main Terminal 2				
Gate				
No Connection				

ORDERING INFORMATION

Device	Package	Shipping
BTA25H-600CW3G	TO-220AB (Pb-Free)	50 Units / Rail
BTA25H-800CW3G	TO-220AB (Pb-Free)	50 Units / Rail

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

Publication Order Number:

BTA25H-600CW3/D

THERMAL CHARACTERISTICS

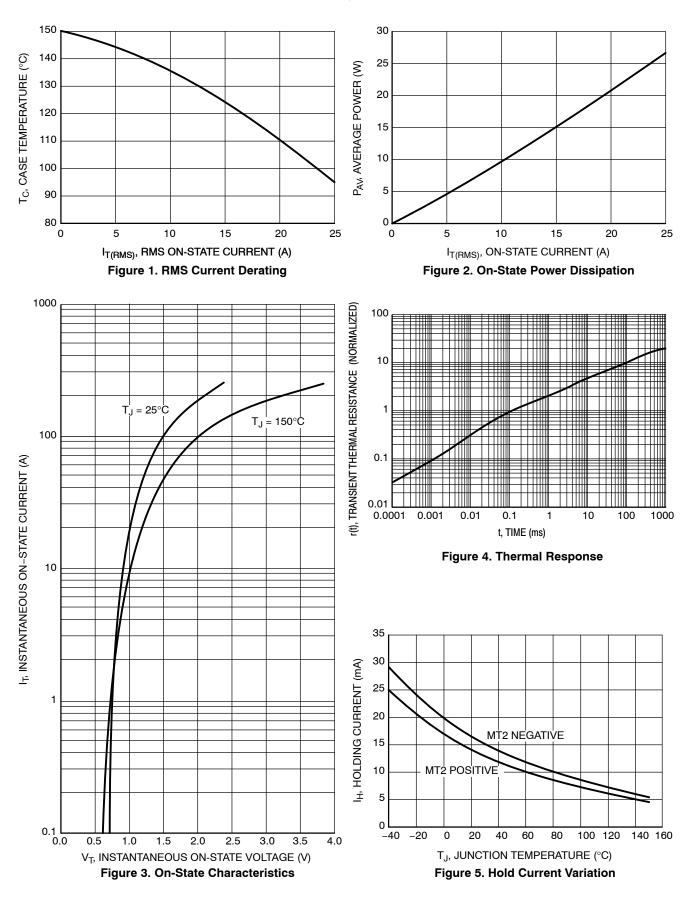
Characteristic	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case (AC) Junction-to-Ambient	$R_{ heta JC} \ R_{ heta JA}$	1.8 60	°C/W
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 seconds	TL	260	°C

ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise noted; Electricals apply in both directions)

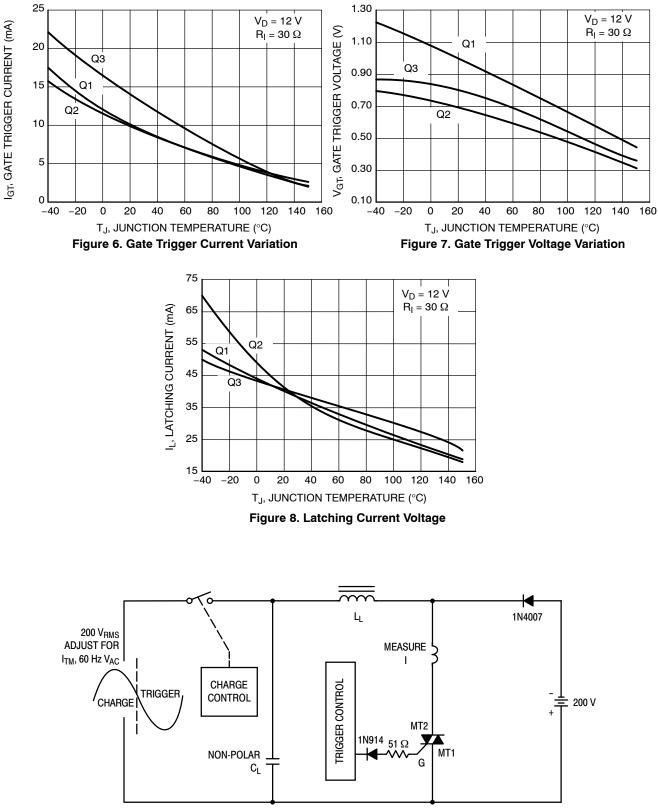
Characteristic			Min	Тур	Max	Unit
OFF CHARACTERISTICS		•				
Peak Repetitive Blocking Current (V _D = Rated V _{DRM} , V _{RRM} ; Gate Open)	T _J = 25°C T _J = 150°C	I _{DRM} , I _{RRM}			0.005 15	mA
ON CHARACTERISTICS						•
Peak On-State Voltage (Note 2) $(I_{TM} = \pm 35 \text{ A Peak})$		V _{TM}	-	-	1.55	V
Gate Trigger Current (Continuous dc) (V _D = 12 V, R _L = 30 Ω) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)		I _{GT}			35 35 35	mA
Holding Current ($V_D = 12 V$, Gate Open, Initiating Current = ±100 mA)		Iн	-	-	50	mA
Latching Current (V _D = 12 V, I_G = 42 mA) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)		ι _L	- - -	_ _ _	75 75 75	mA
Gate Trigger Voltage (V _D = 12 V, R _L = 30 Ω) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)		V _{GT}			1.3 1.3 1.3	V
Gate Non-Trigger Voltage ($T_J = 150^{\circ}C$) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)		V _{GD}	0.15 0.15 0.15			V
DYNAMIC CHARACTERISTICS						
Rate of Change of Commutating Current, See Figure 10. (Gate Open, T_J = 150°C, No Snubber)		(dl/dt) _c	4.0	-	-	A/ms
Critical Rate of Rise of On–State Current $(T_J = 150^{\circ}C, f = 120 \text{ Hz}, I_G = 2 \text{ x } I_{GT}, tr \le 100 \text{ ns})$		dl/dt	-	-	50	A/μs
Critical Rate of Rise of Off-State Voltage $(V_D = 0.66 \times V_{DRM}, Exponential Waveform, Gate Open, T_J = 15)$	50°C)	dV/dt	500	-	-	V/μs

2. Indicates Pulse Test: Pulse Width \leq 2.0 ms, Duty Cycle \leq 2%.

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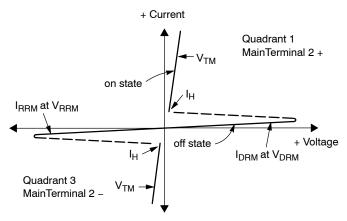
Note: Component values are for verification of rated (di/dt)_c. See AN1048 for additional information.

Figure 9. Simplified Test Circuit to Measure the Critical Rate of Rise of Commutating Current (di/dt)c

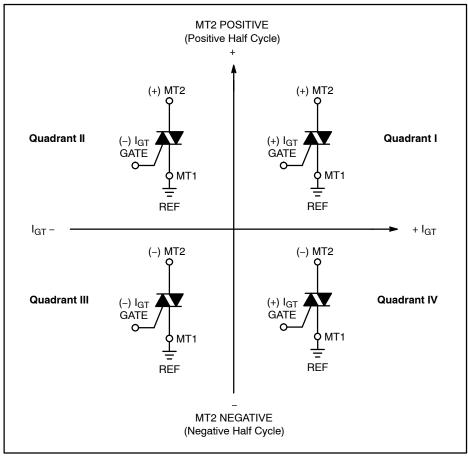
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Voltage Current Characteristic of Triacs (Bidirectional Device)

Symbol	Parameter
V _{DRM}	Peak Repetitive Forward Off State Voltage
I _{DRM}	Peak Forward Blocking Current
V _{RRM}	Peak Repetitive Reverse Off State Voltage
I _{RRM}	Peak Reverse Blocking Current
V _{TM}	Maximum On State Voltage
I _H	Holding Current



Quadrant Definitions for a Triac



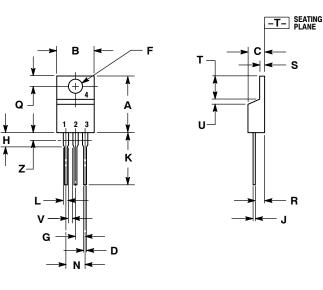
All polarities are referenced to MT1.

With in-phase signals (using standard AC lines) quadrants I and III are used.

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PACKAGE DIMENSIONS

TO-220 CASE 221A-07 **ISSUE AA**



NOTES

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.

2

3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
C	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
Н	0.110	0.155	2.80	3.93
J	0.014	0.022	0.36	0.55
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
Т	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045		1.15	
Z		0.080		2.04

STYLE 12:

PIN 1. MAIN TERMINAL 1 2. MAIN TERMINAL 2

3 GATE NOT CONNECTED 4.

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